

2017

BluGlass Annual General Meeting

MONDAY 13 NOVEMBER 2017

2017

The image is a circular frame, resembling a lens or a porthole, showing a vibrant, abstract landscape. The sky is a deep purple, transitioning into a bright orange and red horizon. The ground is a mix of red and orange, with several dark, circular shapes scattered across it, possibly representing rocks or water. The overall effect is that of a view through a magnifying glass or a lens, with the circular frame being dark and slightly blurred at the edges.

**CHAIRMAN ADDRESS:
THE BLUGLASS VISION**
DR. WILLIAM JOHNSON

OUR VISION

Creating a brighter future, through the impacts of lower temperature RPCVD



OUR VISION

*OUR VISION IS TO ESTABLISH THE **RPCVD** TECHNOLOGY AS A KEY PART OF THE MANUFACTURING SOLUTION FOR HIGH PERFORMANCE OPTO-ELECTRONIC & POWER ELECTRONIC DEVICES TO HELP DRIVE THE **INNOVATIONS OF THE FUTURE.***



OUR MISSION

*OUR MISSION IS TO SEE **RPCVD** EMERGE AS THE PERFORMANCE ENHANCING **TECHNOLOGY OF CHOICE** FOR THE LED & POWER ELECTRONICS INDUSTRIES.*



THE RPCVD BREAKTHROUGH

RPCVD – Remote Plasma Chemical Vapour Deposition



BENEFITS



Lower temperature
manufacturing processes



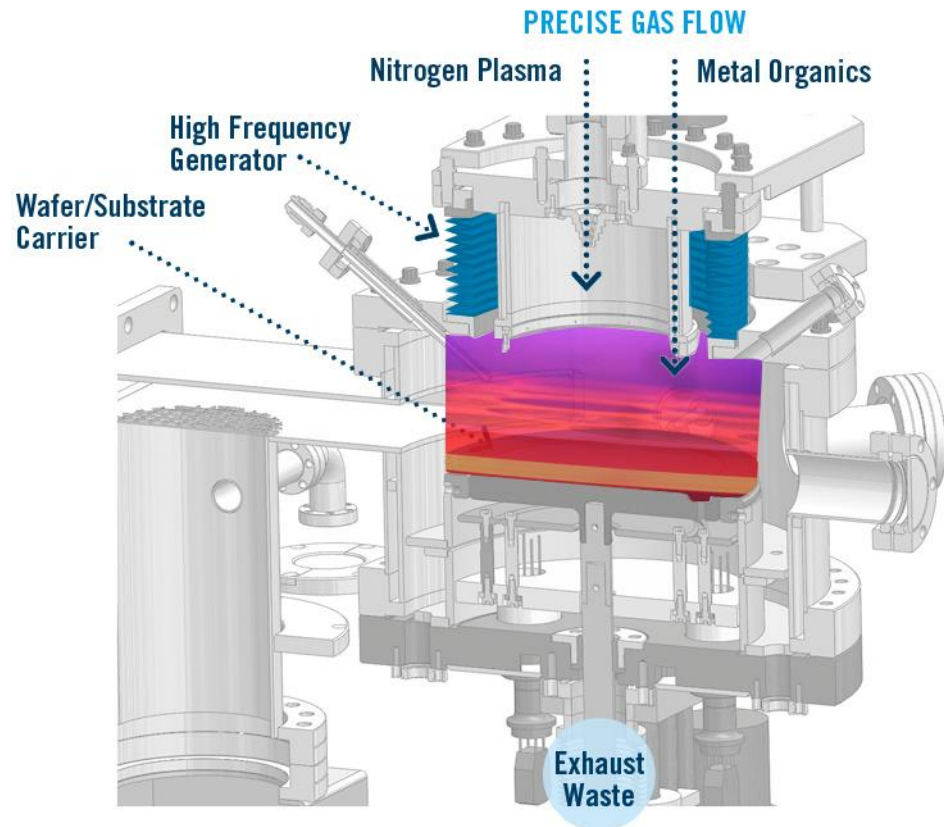
Lower cost inputs



Higher performing
devices



More Environmentally
friendly & sensitive



INTRODUCING EPIBLU



*Revenue
generating business*



Growing customer pipeline



Highly strategic vehicle



PROGRESS TOWARDS COMMERCIALISATION



APPLICATIONS

Exclusive novel LED application

Electronic applications

Green LEDs
Power electronics (HEMT)

Green LEDs
Blue LEDs

Custom Epitaxy
(MOCVD & RPCVD)
Contract R&D

COLLABORATION PROGRESS

LUMILEDS PHASE I

LUMILEDS PHASE II



COMMERCIAL OUTCOMES/ REVENUE



THE YEAR AHEAD



Complete industry evaluations



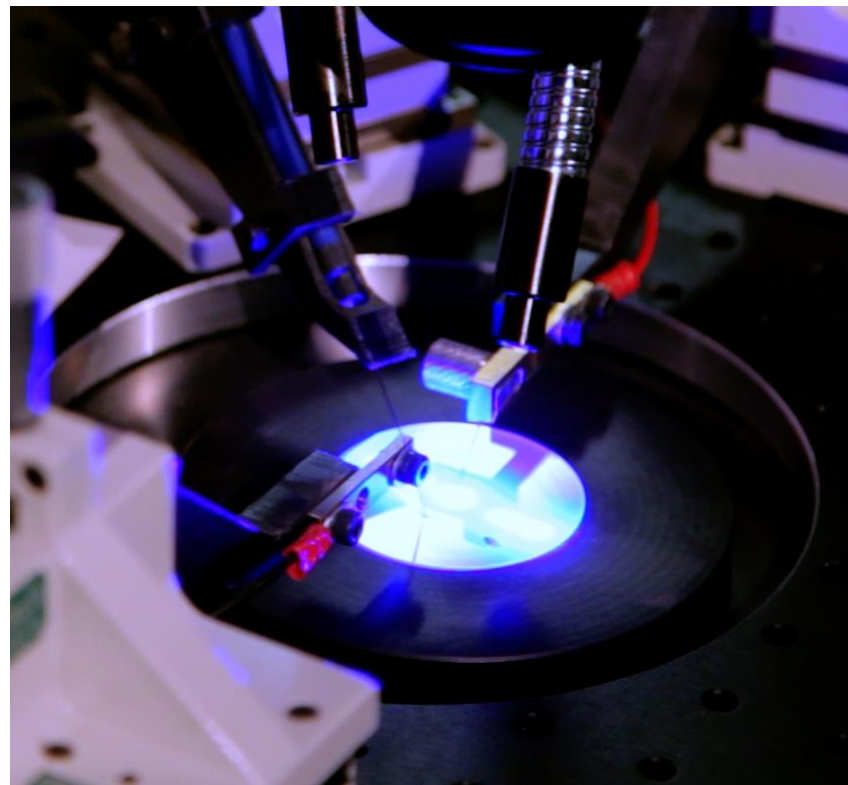
Select more partners/collaborators



Generate and protect more IP



Achieve commercial outcome

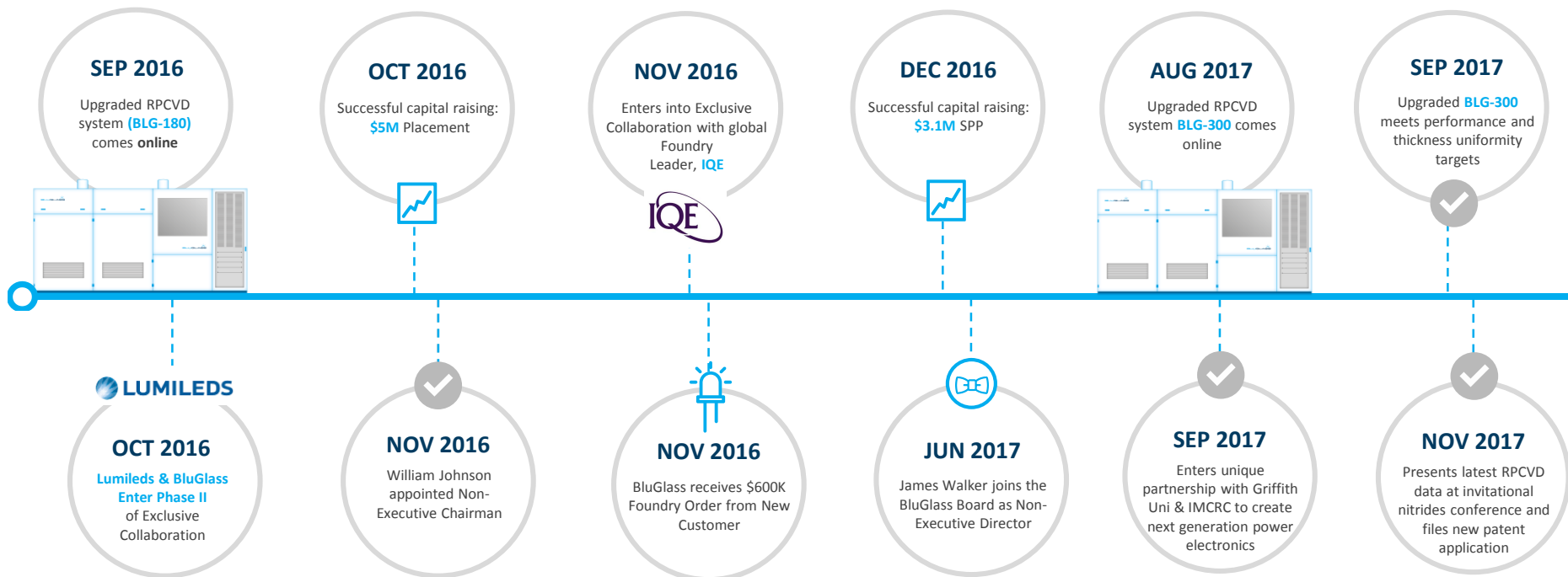




**MANAGING DIRECTOR ADDRESS:
2017 HIGHLIGHTS & THE YEAR AHEAD**
GILES BOURNE

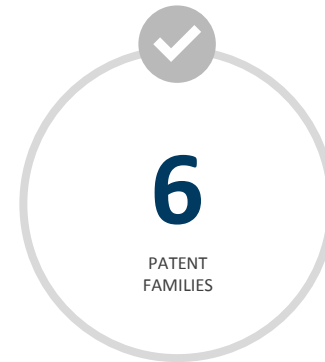
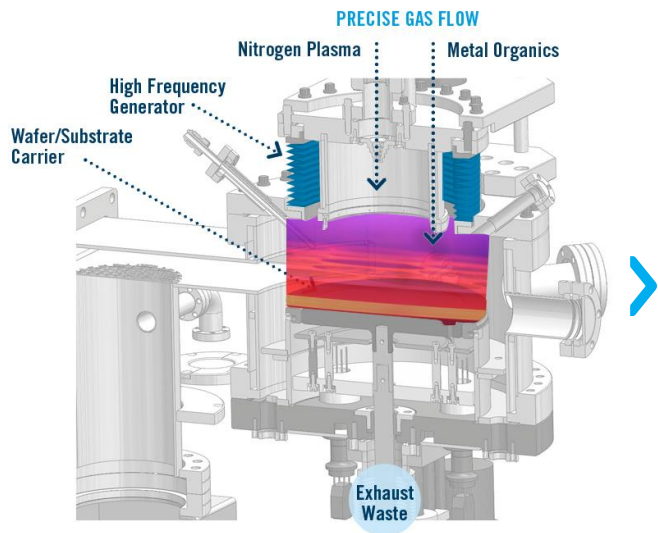
2017 HIGHLIGHTS

BluGlass has made significant technical progress in bringing RPCVD towards commercialisation



IP PORTFOLIO

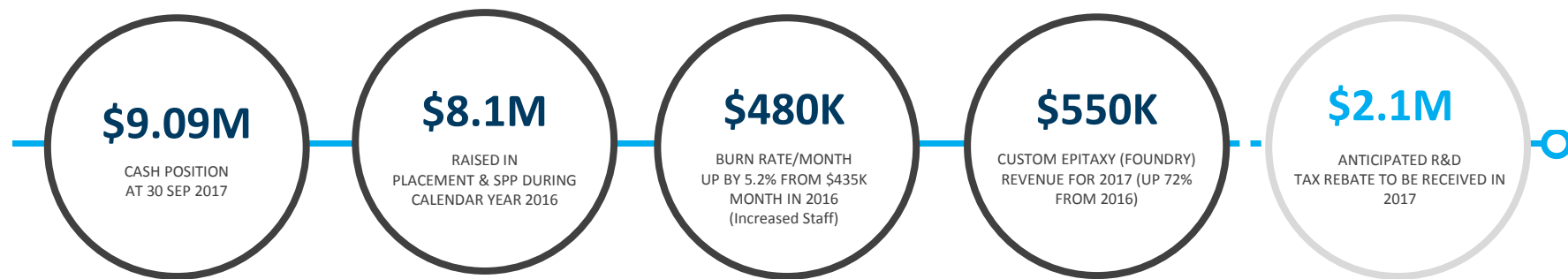
Hardware & Process Patents



FINANCIAL PERFORMANCE

CURRENT POSITION

FORECAST POSITION



BluGlass has a robust cash position to deliver initial commercialisation outcomes

2.5YRS CASH RUNWAY





“THE LUMILEDS / BLUGLASS PROJECT
IS MAKING GOOD PROGRESS.
WE REMAIN FULLY COMMITTED TO
THIS KEY PROJECT”

— LUMILEDS

LUMILEDS COLLABORATION - PHASE II PROGRESS

Exclusive collaboration agreement with market leader—device manufacturer



RPCVD EVALUATION

STATUS

Collaboration is focused on a **novel application of RPCVD for LEDs**



Phase I Complete



Phase II progressing well

PARTNERSHIP WITH WORLD LEADING LED COMPANY TO DEVELOP NOVEL LED APPLICATIONS

Phase II is working to integrate BluGlass' RPCVD technology into certain Lumileds LED applications



Lumileds and BluGlass are both pleased with the progress of Phase II and are confident in the project achievement



IQE COLLABORATION

Strategic Partnership with world leading foundry manufacturer of advanced semiconductor wafer products to the global semiconductor industry



**PARTNERSHIP WITH WORLD LEADING
FOUNDRY TO DEVELOP A RANGE OF
ELECTRONIC APPLICATIONS**



*Exclusive Collaboration Agreement to co-develop nitride films for a **range of electronic devices** on both silicon and IQE's cREO™ technology using BluGlass' unique low temperature RPCVD technology*



***IQE products are used by major global chip companies** to produce the high performance components that enable a wide range of high-tech applications including for the wireless industry*



Positive collaboration is ongoing and both companies remain committed to achieving the technology goals



VEECO & HC SEMITEK EVALUATIONS – RECENTLY RECOMMENCED



**RPCVD EVALUATION WITH
WORLDS LARGEST MOCVD
EQUIPMENT MANUFACTURER**

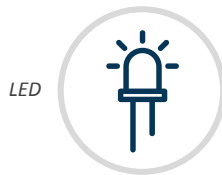


**LEADING CHINESE
LED COMPANY EXPLORING RPCVD
FOR MULTIPLE APPLICATIONS**

RPCVD EVALUATION

STATUS

Positive initial 2 inch trials
for green LEDs



LED

Power
Electronics

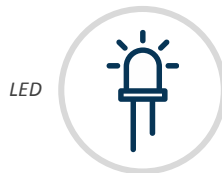


Recently upgraded BLG-300 with
uniformity over 4 & 6" wafers has
enabled this evaluation to recommence

RPCVD EVALUATION

STATUS

*Targeting enhanced performance
and lower cost LEDs using RPCVD*



LED

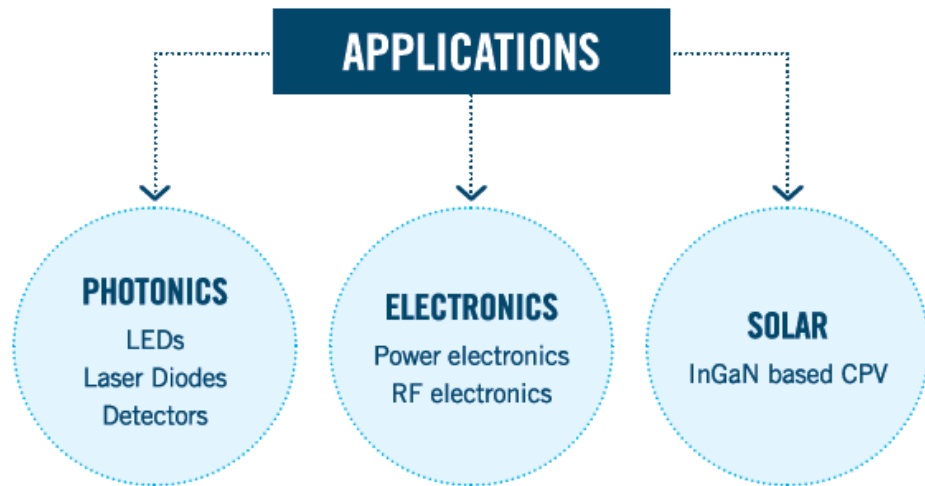
Recently upgraded BLG-300 with
uniformity over 4 & 6" wafers has
enabled this evaluation to recommence



EPIBLU – CUSTOM EPITAXY SERVICE BUSINESS



- ✓ *Multiple customers*
- ✓ *Growing pipeline of new customers*
- ✓ *Providing both MOCVD & RPCVD services*
- ✓ *Conducting services for green and blue LEDs, power electronics, and laser diodes*



END MARKETS LED

10.4%

The LED market is expected to experience *CAGR of 10.4%* through to 2025

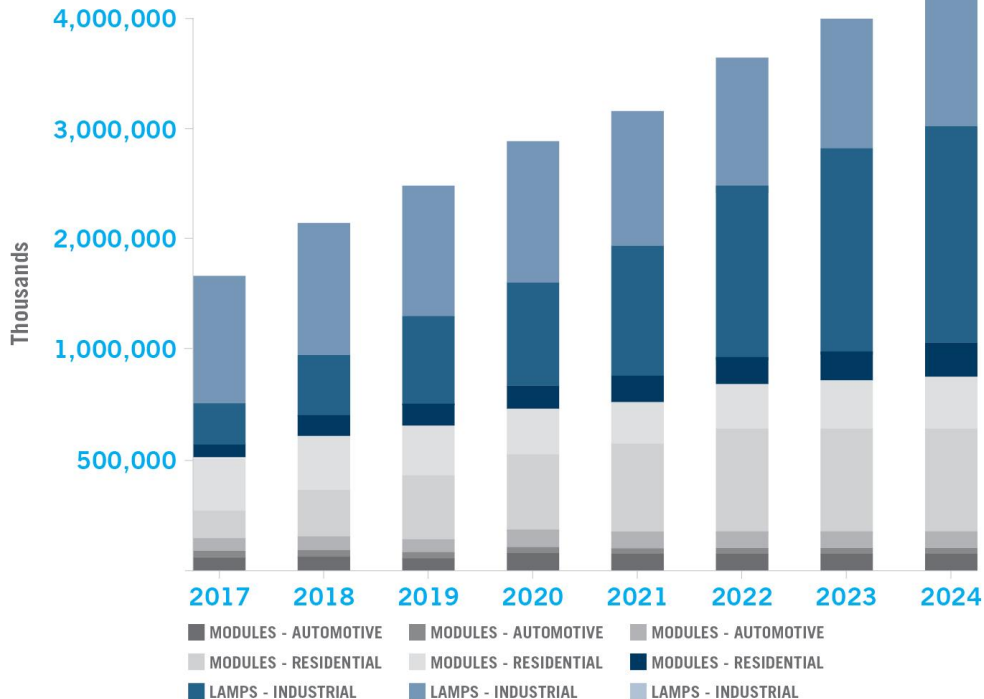


\$63.2B

LED revenues are expected to reach *\$63.2 billion* by 2025

Source: Research and Markets Report *Global Light-Emitting Diodes (LED) Market Analysis & Trends - Industry Forecast to 2025*; and Navigant Research

UNIT SHIPMENTS OF LED LAMPS & MODULES BY END USE, WORLD MARKETS: 2017 - 2024



SOURCE: Navigant Research, LED Lighting: Global Outlook Report September 2015



END MARKETS POWER ELECTRONICS

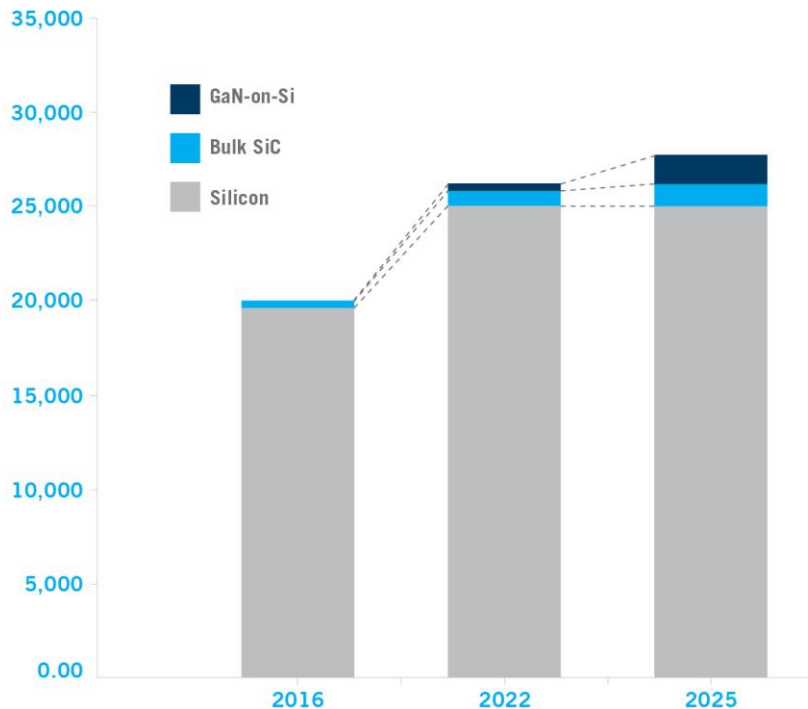
The Power Electronics markets also presents a growing opportunity for the RPCVD technology

\$2.6B

The GaN and SiC power electronics market is expected to be worth \$2.6B by 2022

GaN for power semiconductors is expected to grow at

~90% CAGR
to 2022

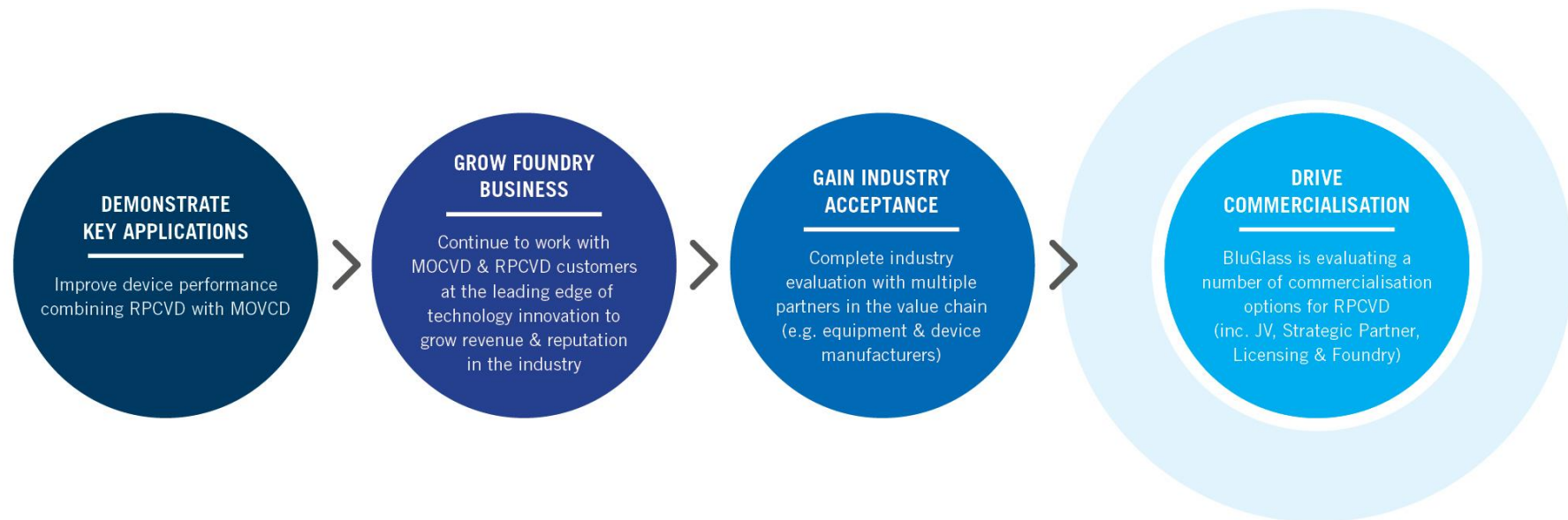


Source: Stifel, Sep 2017; and Research and Markets



PATH TO MARKET

BluGlass continues to be active in all four segments of its path to market



CONCLUSION INVESTMENT HIGHLIGHTS



Disruptive
platform
technology

*LED,
Power &
Solar*

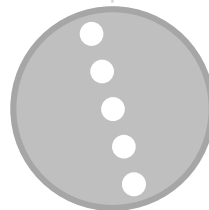


Multiple,
growing end
markets



Well funded,
approaching
commercialisation

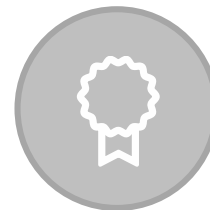
*Sales from
Services*



High end
service
capability



A team with global
leading expertise in
semiconductors



Multiple
awards &
grants





**CHIEF OPERATIONS & TECHNOLOGY OFFICER ADDRESS:
SIGNIFICANT TECHNICAL PROGRESS IN 2017**

DR. IAN MANN

LUMILEDS PHASE II AND OTHER INDUSTRY COLLABORATIONS



Lumileds pleased with progress
and are committed to project



A number of iterations of BluGlass wafers
have been fabricated **at Lumileds**



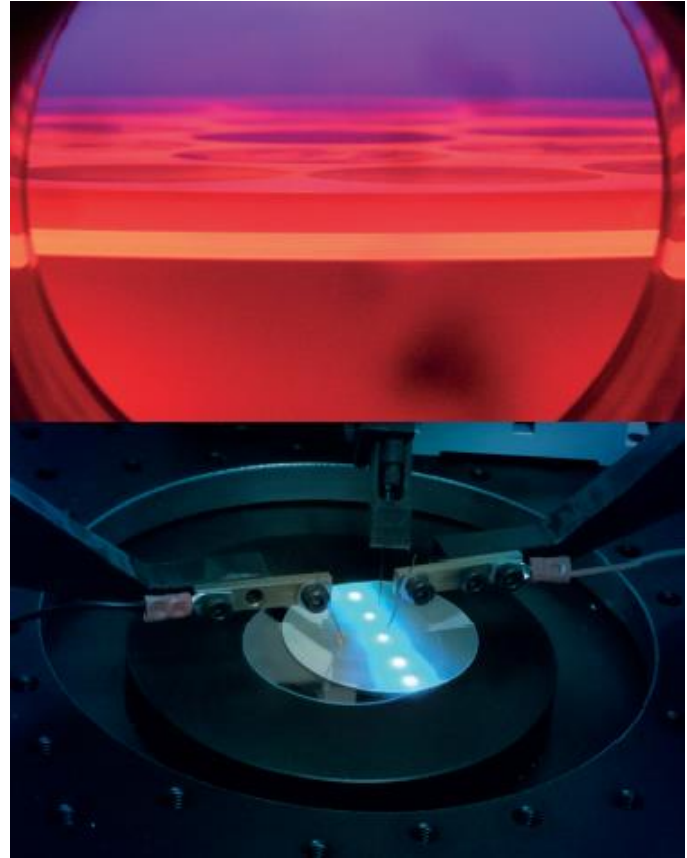
Both RPCVD systems with the latest
chamber design are delivering on technical
roadmap for Lumileds project



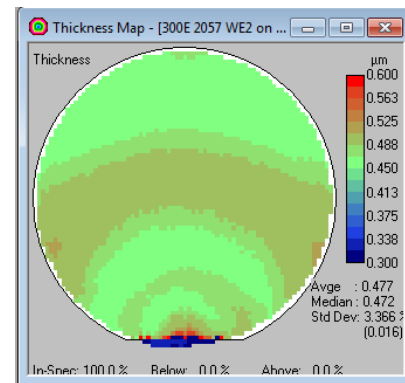
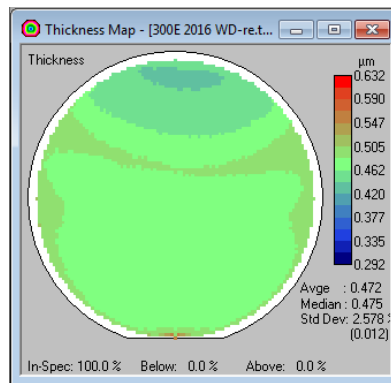
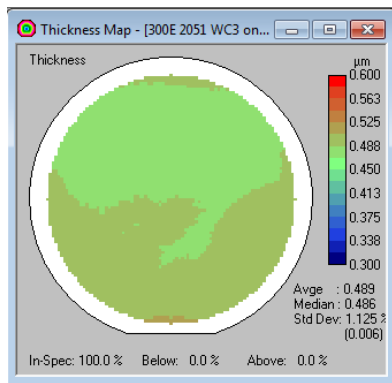
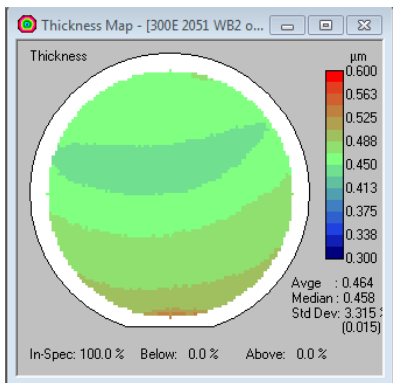
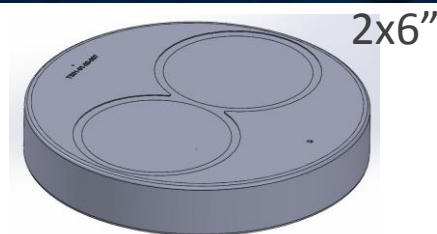
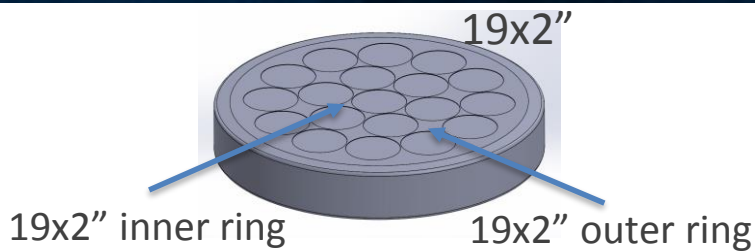
HC Semitek, IQE, and Veeco collaborations are
all **recommencing with the success of the
upgraded BLG-300 RPCVD capability**



BluGlass has filed a patent



BLG-300 RPCVD CHAMBER UPGRADE – THICKNESS UNIFORMITY IMPROVEMENT



WAFER DIAMETER	2" (OUTER)	2" (INNER)	100 mm	150 mm
2017 CHAMBER (THICKNESS STD DEV %)	1.1	3.3	2.6	3.4
2016 CHAMBER (THICKNESS STD DEV %)	6.8	7.8	10.9	--





CUSTOM GaN EPITAXY & CONTRACT R&D SERVICES

MOCVD & Low Temperature RPCVD Foundry Services:

Advanced semiconductor wafer products including: LED, LD, Power Electronics, RF and more

Advanced R&D capabilities

Low volume foundry & prototyping

Characterisation services



Targeting strategic customers requiring both **RPCVD** and **MOCVD** combined



BluGlass has repeat customers developing applications in both LEDs and Laser Diodes



BluGlass has enhanced several demonstrators using our in-house RPCVD and MOCVD capabilities to market to the industry



Recently showcased several **Key Demonstrators** at the recent semiconductor conference



RPCVD TECHNOLOGY DEVELOPMENT AREAS

RPCVD DIFFERENTIATOR	BLUE LEDES	GREEN LEDES	LASER DIODES	RGB MICRO - LEDES AND SOLAR	UV LEDES	POWER ELECTRONICS	ELECTRONICS APPLICATIONS
p-GaN	●	●●	●●	●		●●	
p-AlGaIn	●	●	●●	●	●		
InGaIn	●	●	●	●			
AlN / Silicon							●●
AlN / sapphire	●●				●		



BluGlass active collaborations and/or customers

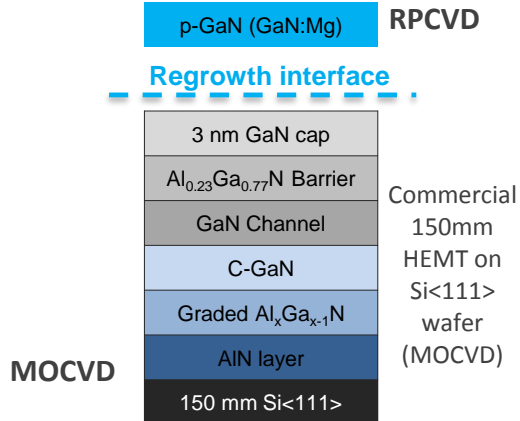


BluGlass active areas in discussions with potential collaborators and/or customers

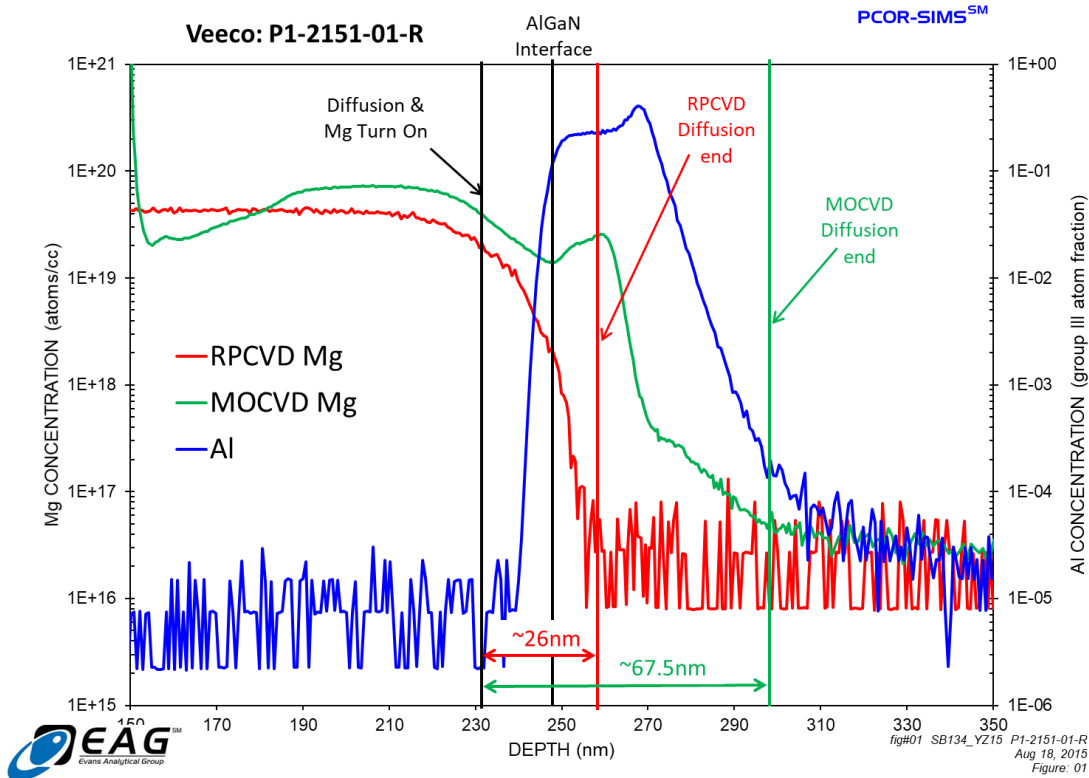


RPCVD p-GaN FOR E-MODE HEMTs – COLLABORATION WITH VEECO

RPCVD VS. MOCVD p-GaN: Mg DIFFUSION IN HEMTs



Note the Mg SIMS trace for the MOCVD growth is overlaid on the RPCVD p-GaN on HEMT SIMS trace for ease of comparison. The Al traces from the 2DEG (common to both structures) was used for alignment purposes.



KEY DEMONSTRATOR: RPCVD p-GaN + MOCVD FOR GREEN LEDs

LED STRUCTURE GROWN USING MOCVD

p-GaN grown at **INTERMEDIATE to HIGH** temperature



Multi-Quantum-Well (MQW) InGaN layer, the **ACTIVE REGION** of an LED – grown at low temperature



n-GaN grown at high temperature

GaN grown at high temperature

Sapphire Substrate

p-GaN GROWN USING RPCVD

p-GaN grown at **LOW** temperature



Multi-Quantum-Well (MQW) InGaN layer, the **ACTIVE REGION** of an LED – grown at low temperature



n-GaN grown at high temperature

GaN grown at high temperature

Sapphire Substrate

RPCVD

MOCVD



KEY DEMONSTRATOR: RPCVD p-GaN + MOCVD FOR GREEN LEDs

2016 AGM DATA

MOCVD* EL DATA	20 mA
Light Output (mW)	1.3
V_f (V)	3.5
Peak Wavelength (nm)	525
FWHM (nm)	35

RPCVD* EL DATA	20 mA
Light Output (mW)	1.6
V_f (V)	3.9
Peak Wavelength (nm)	525
FWHM (nm)	33

% Performance improvement of
RPCVD compared to MOCVD
[Light Output / (I x Vf)]

+10%

* MOCVD data from best results for complete LED structure grown without any interruption and using a p-AlGaIn EBL. RPCVD data taken from best results overgrown on equivalent MOCVD-grown MQWs. RPCVD samples do not contain an EBL. All measurements taken at wafer level using indium dot contacts.

2017 DATA **

MOCVD EL DATA	20 mA	50 mA	100 mA
Light Output (mW)	1.3	3.3	6.2
V_f (V)	3.1	3.7	4.6
Peak Wavelength (nm)	514	511	508
FWHM (nm)	28	31	33

RPCVD EL DATA	20 mA	50 mA	100 mA
Light Output (mW)	1.9	4.5	8.1
V_f (V)	3.0	3.6	4.5
Peak Wavelength (nm)	515	512	510
FWHM (nm)	30	30	33

% Performance improvement of
RPCVD compared to MOCVD
[Light Output / (i x Vf)]

+47%

+39%

+35%

** Both RPCVD and MOCVD data obtained from p-GaN overgrown on the same partial LEDs grown by MOCVD up to and including the EBL. All measurements taken at wafer level using indium dot contacts.



KEY DEMONSTRATOR: RPCVD p-GaN + RPCVD MQWs FOR RGB LEDs

LED STRUCTURE GROWN USING MOCVD

p-GaN & MQW GROWN USING RPCVD

MOCVD

p-GaN grown at **INTERMEDIATE** to **HIGH** temperature



Multi-Quantum-Well (MQW) InGaN layer, the **ACTIVE REGION** of an LED – grown at low temperature



n-GaN grown at high temperature

GaN grown at high temperature

Sapphire Substrate

p-GaN grown at **LOW** temperature



Multi-Quantum-Well (MQW) InGaN layer, the **ACTIVE REGION** of an LED – grown at low temperature



n-GaN grown at high temperature

GaN grown at high temperature

Sapphire Substrate

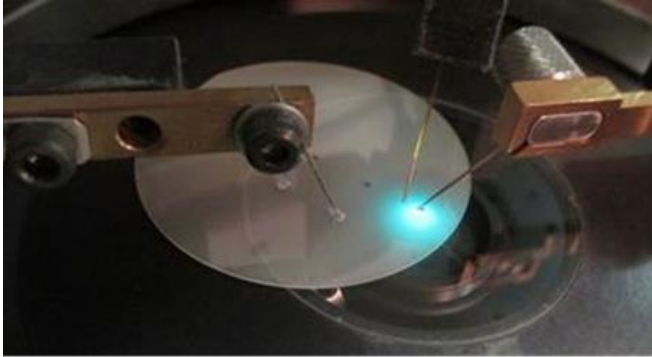
RPCVD

MOCVD



KEY DEMONSTRATOR: RPCVD MQWs for RGB LEDs

RPCVD MQW BASED LED 2016

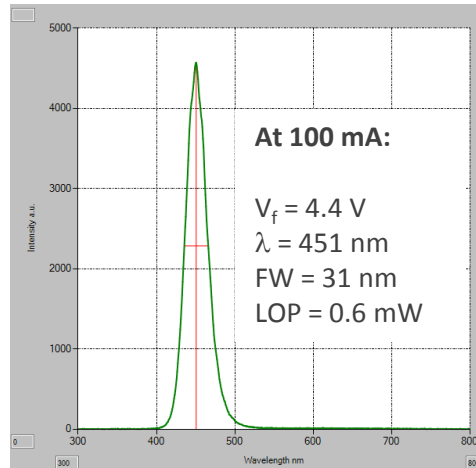
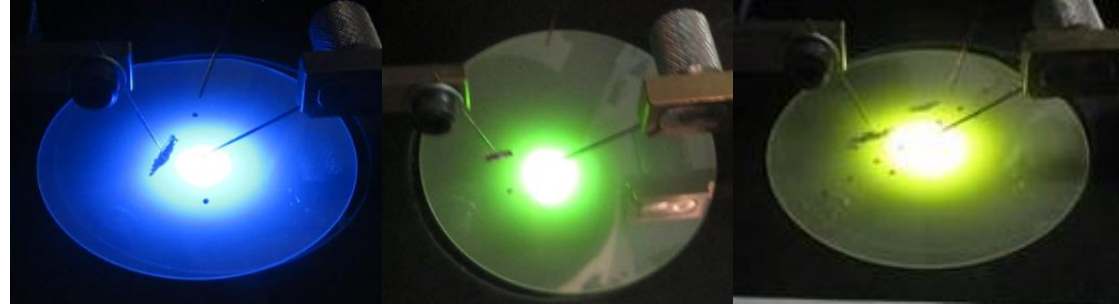


To attract further industry interest BluGlass continues to enhance the RPCVD capability



Low temperature RPCVD is favourable for In rich InGaN MQWs useful for longer wavelength LEDs

RPCVD MQW BASED LEDs 2017



Micro-LED players have shown interest in RPCVD capability for blue, green, yellow and red LEDs for display and other applications



KEY DEMONSTRATOR: RGB RPCVD FOR MICRO-LEDs AND SOLAR APPLICATIONS

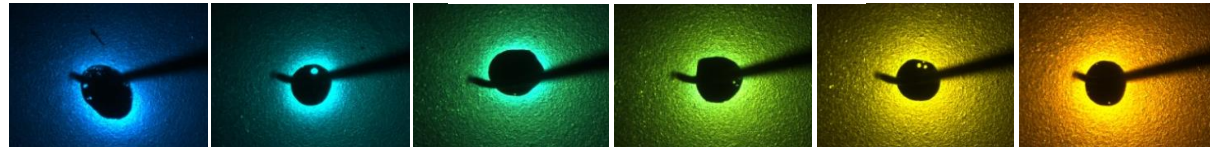
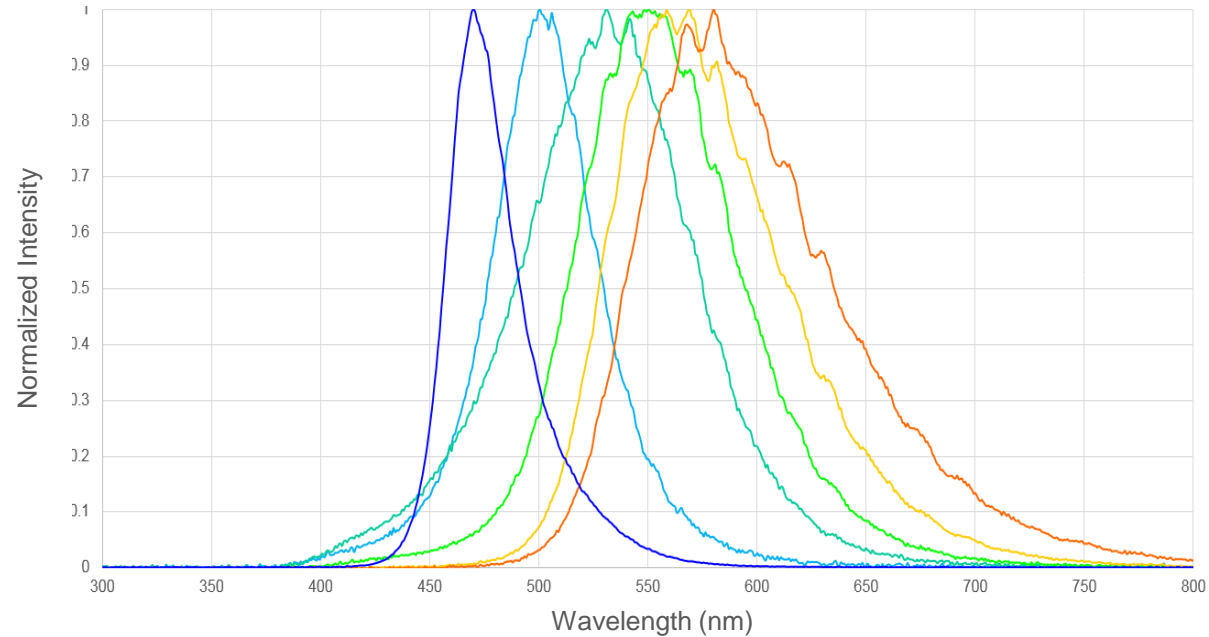


Preliminary RPCVD demonstration of RGB LED capability



RPCVD MQW capability is also a key step to the realisation of high efficiency solar cells through multi junction architecture

EL SPECTRA OF LEDs GROWN USING RPCVD MQWS





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